ON Semiconductor

Is Now

Onsemi

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N-Channel Power MOSFET 500 V, 3.3 Ω

Features

- Low ON Resistance
- Low Gate Charge
- ESD Diode-Protected Gate

Rating

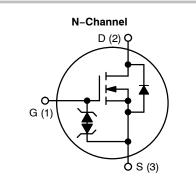
- 100% Avalanche Tested
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

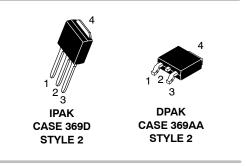


ON Semiconductor®

http://onsemi.com

V _{DSS}	R _{DS(on)} (MAX) @ 1.15 A
500 V	3.3 Ω





ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Symbol

Value

Unit

Drain-to-Source Voltage	V _{DSS}	500	V
Continuous Drain Current $R_{\theta JC}$	Ι _D	2.6	А
Continuous Drain Current $R_{\theta JC}$, $T_A = 100^{\circ}C$	۱ _D	1.7	A
Pulsed Drain Current, $V_{GS} \mathbin{@} 10 \ V$	I _{DM}	10	А
Power Dissipation $R_{\theta JC}$	PD	58	W
Gate-to-Source Voltage	V _{GS}	±30	V
Single Pulse Avalanche Energy, $I_D = 2.6 A$	E _{AS}	120	mJ
ESD (HBM) (JESD22-A114)	V _{esd}	2000	V
Peak Diode Recovery	dv/dt	4.5 (Note 1)	V/ns
Continuous Source Current (Body Diode)	I _S	2.6	A
Maximum Temperature for Soldering Leads	ΤL	260	°C
Operating Junction and Storage Temperature Range	T _J , T _{stg}	–55 to 150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. $I_D \leq 2.6$ A, di/dt ≤ 200 A/ μ s, V_{DD} \leq BV_{DSS}, T_J $\leq 150^{\circ}$ C.

MARKING AND ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

THERMAL RESISTANCE

Parameter			Value	Unit
Junction-to-Case (Drain)	NDD03N50Z	$R_{\theta JC}$	2.2	°C/W
Junction-to-Ambient Steady State	(Note 3) NDD03N50Z (Note 2) NDD03N50Z-1	R_{\thetaJA}	41 80	

2. Insertion mounted

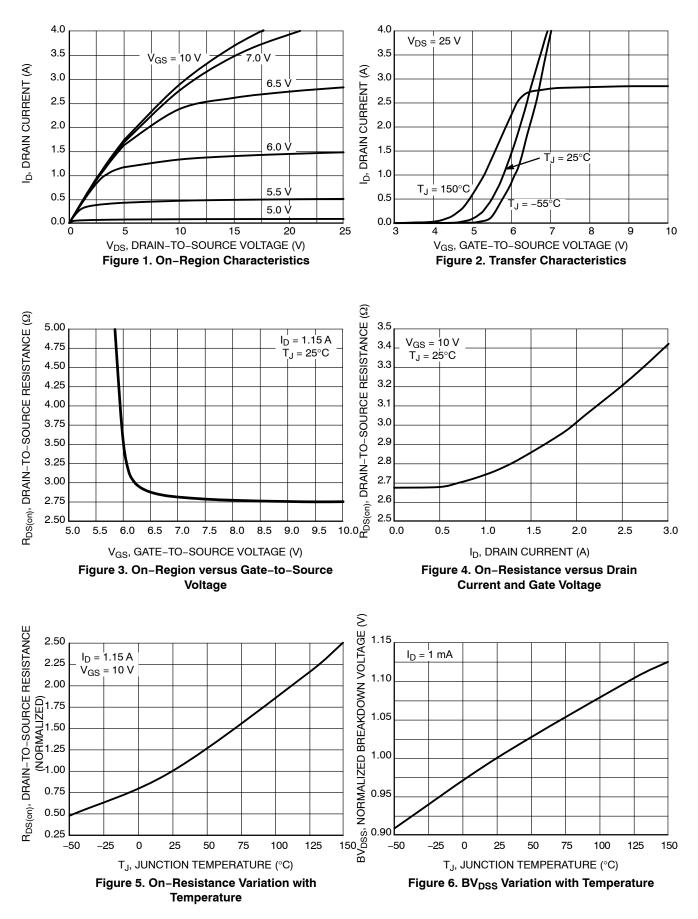
3. Surface mounted on FR4 board using 1" sq. pad size, (Cu area = 1.127 in sq [2 oz] including traces).

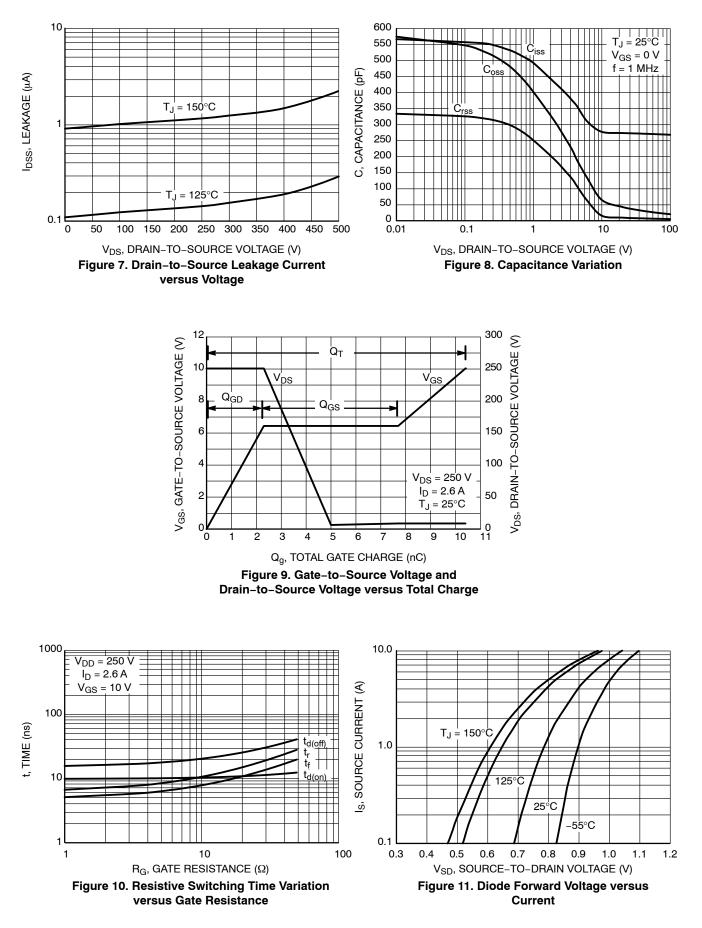
ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise noted)

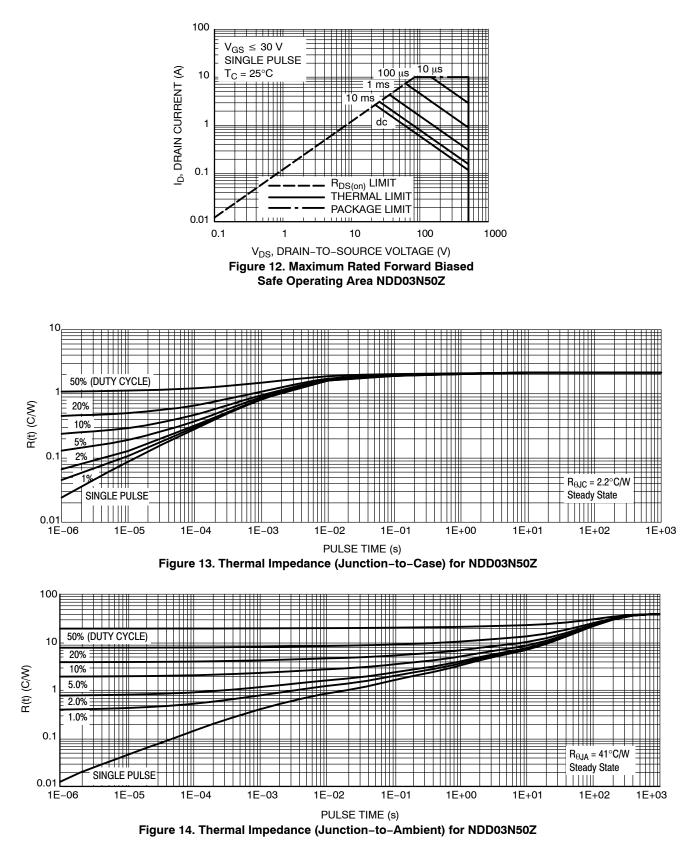
Characteristic	Symbol	Test Conditions		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	BV _{DSS}	V _{GS} = 0 V, I _D = 1 m	ıΑ	500			V
Breakdown Voltage Temperature Coefficient	$\Delta \text{BV}_{\text{DSS}}/$ $\Delta \text{T}_{\text{J}}$	Reference to 25°C I _D = 1 mA),		0.6		V/°C
Drain-to-Source Leakage Current	I _{DSS}		25°C			1.0	μA
		$V_{DS} = 500 \text{ V}, V_{GS} = 0 \text{ V}$	150°C			50	1
Gate-to-Source Forward Leakage	I _{GSS}	V _{GS} = ±20 V				±10	μA
ON CHARACTERISTICS (Note 4)					-	-	-
Static Drain-to-Source On-Resistance	R _{DS(on)}	V _{GS} = 10 V, I _D = 1.1	5 A		2.8	3.3	Ω
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 50$	μA	3.0		4.5	V
Forward Transconductance	9 _{FS}	V _{DS} = 15 V, I _D = 1.1	5 A		1.8		S
DYNAMIC CHARACTERISTICS							
Input Capacitance (Note 5)	C _{iss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz		219	274	329	pF
Output Capacitance (Note 5)	C _{oss}			28	38	50	
Reverse Transfer Capacitance (Note 5)	C _{rss}			6.0	8.0	10	
Total Gate Charge (Note 5)	Qg			5.0	10	16	nC
Gate-to-Source Charge (Note 5)	Q _{gs}	V _{DD} = 250 V, I _D = 2.6	6 A,	1.2	2.3	4.0	1
Gate-to-Drain ("Miller") Charge (Note 5)	Q _{gd}	V _{GS} = 10 V	-	3.2	5.5	8.0	1
Plateau Voltage	V _{GP}				6.4		V
Gate Resistance	R _g			1.5	4.5	13.5	Ω
RESISTIVE SWITCHING CHARACTERISTI	cs						
Turn-On Delay Time	t _{d(on)}				9.0		ns
Rise Time	t _r	V_{DD} = 250 V, I_D = 2.6 A, V_{GS} = 10 V, R_G = 5 Ω			7.0		1
Turn-Off Delay Time	t _{d(off)}				15		1
Fall Time	t _f				7.0		1

Diode Forward Voltage	V _{SD}	$I_{\rm S}$ = 2.6 A, $V_{\rm GS}$ = 0 V		1.6	V
Reverse Recovery Time	t _{rr}	$V_{GS} = 0 V, V_{DD} = 30 V$	240		ns
Reverse Recovery Charge	Q _{rr}	I _S = 2.6 A, di/dt = 100 A/μs	0.7		μC

4. Pulse Width \leq 380 μ s, Duty Cycle \leq 2%. 5. Guaranteed by design.





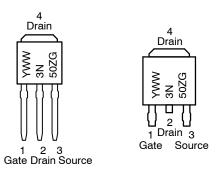


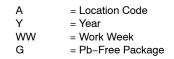
ORDERING INFORMATION

Order Number	Package	Shipping [†]
NDD03N50Z-1G	IPAK (Pb-Free)	75 Units / Rail
NDD03N50ZT4G	DPAK (Pb-Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MARKING DIAGRAMS





SCALE 1:1

STYLE 1: PIN 1. BASE

2. COLLECTOR

4. COLLECTOR

3. EMITTER

STYLE 5: PIN 1. GATE 2. ANODE 3. CATHODE

4. ANODE

DATE 15 DEC 2010



IPAK CASE 369D-01 **ISSUE C** С в -ν Ε R 7 4 Α S 2 3 1 -T-7 SEATING PLANE κ J F ·H D 3 PL G 🖛 🔶 0.13 (0.005) 🔘 T

> STYLE 3: PIN 1. ANODE

2. CATHODE

4. CATHODE

COLLECTOR

3. ANODE

STYLE 7: PIN 1. GATE 2. COLLECTOR 3. EMITTER

4.

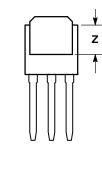
STYLE 2: PIN 1. GATE

STYLE 6: PIN 1. MT1 2. MT2 3. GATE

4. MT2

DRAIN
 SOURCE

4. DRAIN



STYLE 4: PIN 1. CATHODE

ANODE
 GATE

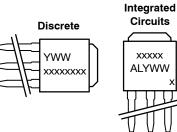
4. ANODE

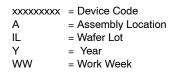
	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.245	5.97	6.35
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
Е	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.090 BSC		2.29	BSC
Н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
κ	0.350	0.380	8.89	9.65
R	0.180	0.215	4.45	5.45
S	0.025	0.040	0.63	1.01
V	0.035	0.050	0.89	1.27
Ζ	0.155		3.93	

 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.

NOTES:

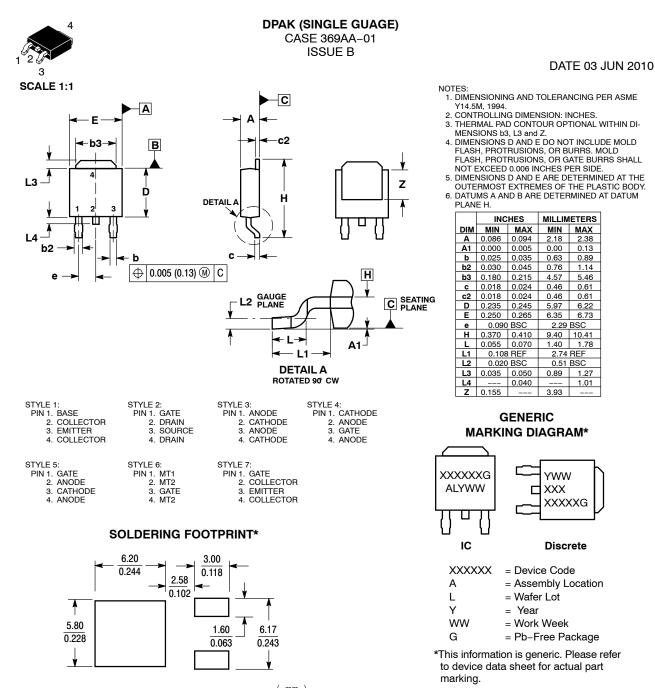
MARKING DIAGRAMS





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SCALE 3:1 $\left(\frac{\text{mm}}{\text{inches}}\right)$

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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